

CORRECTION

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www.rsc.org/advances**Correction: Role of annealing temperature on the sol–gel synthesis of VO_2 nanowires with *in situ* characterization of their metal–insulator transition**

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Correction for 'Role of annealing temperature on the sol–gel synthesis of VO_2 nanowires with *in situ* characterization of their metal–insulator transition' by Y.-R. Jo *et al.*, *RSC Adv.*, 2018, **8**, 5158–5165.

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